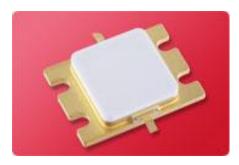


## Features

- High Power: 160W(Typ.) @ Pin=6.3W(38dBm)
- High Efficiency: 62%(Typ.) @ Pin=6.3W(38dBm)
- Broad Band: 2.7 to 3.1GHz
- Impedance Matched Zin/Zout = 50 ohm
- Hermetically Sealed Package: IV-Package

## Description

Sumitomo GaN-HEMT SGN2731-130H-R offers high power, high efficiency and greater consistency for Sband radar applications with 50V operation. The low thermal resistance allows to use long pulse up to 5msec pulse width with duty of 10%.



### ABSOLUTE MAXIMUM RATING (Case Temperature T<sub>c</sub>=25 deg.C)

Item	Symbol	Rating	Unit
Operating Voltage	V <sub>DS</sub>	55	V
Drain-Source Voltage	V <sub>DS</sub>	250 @ V <sub>GS</sub> -10V	V
Gate-Source Voltage	V <sub>GS</sub>	-15	V
Storage Temperature	T <sub>stg</sub>	-55 to +125	deg.C
Channel Temperature	T <sub>ch</sub>	+250	deg.C

#### **RECOMMENDED OPERATING CONDITION**

Item	Symbol	Condition	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>		<=50	V
Forward Gate Current	I <sub>GF</sub>	Rg=12ohm	<=122	mA
Reverse Gate Current	I <sub>GR</sub>	Rg=12ohm	>=-5.2	mA
Peak Channel Temperature	T <sub>ch-peak</sub>		<=200	deg.C
Pulse Width	PW	Duty 10%	<= 5000	µsec
	PVV	Duty 25%	<= 1000	µsec

#### ELECTRICAL CHARACTERISTICS (Case Temperature T<sub>c</sub>=25 deg.C)

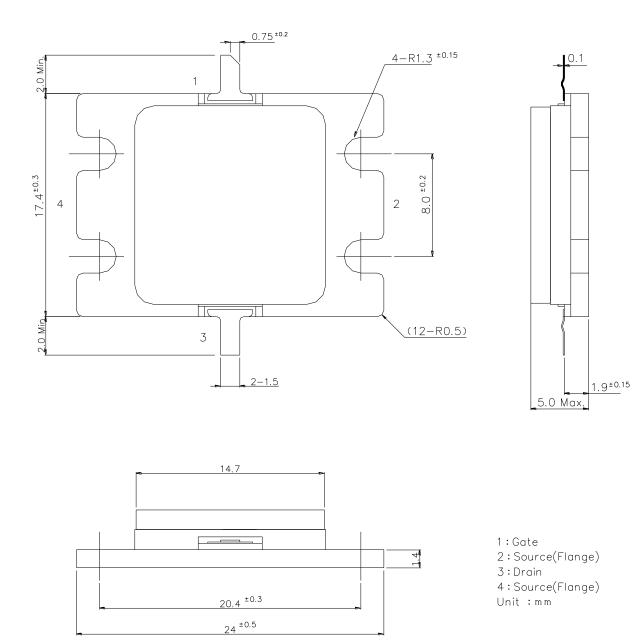
Item	Symbol	Condition	Limit			11
			Min.	Тур.	Max.	Unit
Pinch-off Voltage	VP	$V_{DS}$ =50V, $I_{DS}$ =36mA	-4.0	-3.0	-2.0	V
Output Power	Pout		51.2	52.2	-	dBm
Drain Efficiency	DE	$V_{DS}$ =50V, $I_{DS(DC)}$ =500mA,	-	62.0	-	%
Power Gain	G <sub>P</sub>	Pin=6.3W(38dBm),	13.2	14.2	-	dB
Gain Flatness	GF	f=2.7, 2.8, 2.9, 3.0, 3.1GHz, PW=400µsec, Duty=25%	-	0.8	1.3	%
Load Mismatch Ruggedness	VSWR		10:1	-	-	dB
Thermal Resistance	$R_{th}$	Channel to Case at 45W $P_{DC}$	-	1.1	1.3	deg.C/W
	-					
	T1 /					

CASE STYLE	IV
RoHS Compliance	YES



## Package Outline

# Case Style: IV





## For Safety, Observe the Following Procedures Environmental Management

- Do not put this product into the mouth.
- Do not alter the form of this product into a gas, powder, or liquid through burning, crushing, or chemical processing as these by-products are dangerous to the human body if inhaled, ingested, or swallowed.
- Respect all applicable laws of the country when discarding this product. This product must be disposed in accordance with methods specified by applicable hazardous waste procedures.

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